

S9015

PNP Silicon Low Frequency, Low Noise Amplifier

RoHS Compliant Product

A suffix of "-C" specifies halogen & lead-free

FEATURES

Power dissipation

 P_{CM} : 0.2 W

Collector Current

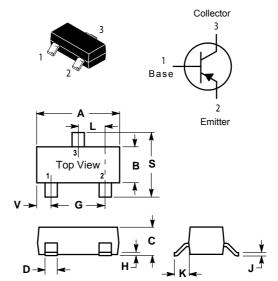
Iсм : -0.1 A

Collector-base voltage

 $V_{\text{(BR)CBO}}$: -50 V

Operating & storage junction temperature

 $T_{j}, T_{stg} : -55^{\circ}C \sim +150^{\circ}C$



| SOT-23 | | | | | |
|---------------------|-------|-------|--|--|--|
| Dim | Min | Max | | | |
| Α | 2.800 | 3.040 | | | |
| В | 1.200 | 1.400 | | | |
| С | 0.890 | 1.110 | | | |
| D | 0.370 | 0.500 | | | |
| G | 1.780 | 2.040 | | | |
| Н | 0.013 | 0.100 | | | |
| J | 0.085 | 0.177 | | | |
| K | 0.450 | 0.600 | | | |
| L | 0.890 | 1.020 | | | |
| S | 2.100 | 2.500 | | | |
| ٧ | 0.450 | 0.600 | | | |
| All Dimension in mm | | | | | |

ELECTRICAL CHARACTERISTICS (Tamp.=25°C unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|-----------------------|---|-----|-----|------|------|
| Collector-base breakdown voltage | V _{(BR)CBO} | Ic= -100μA, I _E =0 | -50 | | | V |
| Collector-emitter breakdown voltage | V _{(BR)CEO} | Ic= -0.1mA, I _B =0 | -45 | | | V |
| Emitter-base breakdown voltage | V _{(BR)EBO} | I _E =-100μΑ, I _C =0 | -5 | | | ٧ |
| Collector cut-off current | I _{CBO} | V _{CB} =-50V, I _E =0 | | | -0.1 | μA |
| Emitter cut-off current | I _{EBO} | V _{EB} = -5V, I _C =0 | | | -0.1 | μA |
| DC current gain | h _{FE(1)} | V _{CE} =-5V, I _C = -1mA | 200 | | 1000 | |
| Collector-emitter saturation voltage | V _{CE} (sat) | I _C =-100mA, I _B = -10mA | | | -0.3 | V |
| Base-emitter saturation voltage | V _{BE} (sat) | I _C =-100mA, I _B =-10mA | | | -1 | V |
| Transition frequency | f⊤ | V _{CE} =-5V, I _C = -10mA f=30MHz | 150 | | | MHz |

CLASSIFICATION OF h_{FE(1)}

| Rank | L | Н |
|-------|---------|----------|
| Range | 200-450 | 450-1000 |

| DEVICE MARKING | S9015 = M6 |
|----------------|------------|
|----------------|------------|

http://www.SeCoSGmbH.com

Any changing of specification will not be informed individual



S9015

PNP Silicon

Low Frequency, Low Noise Amplifier

Typical Characteristics

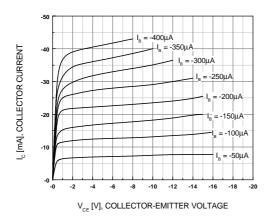


Figure 1. Static Characteristic

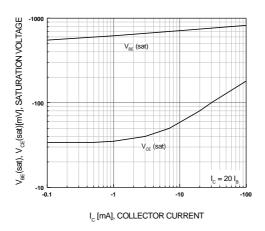


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

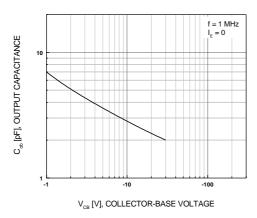


Figure 5. Collector Output Capacitance

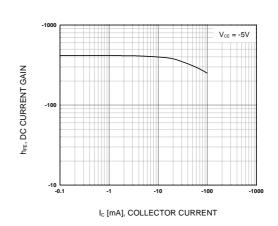


Figure 2. DC current Gain

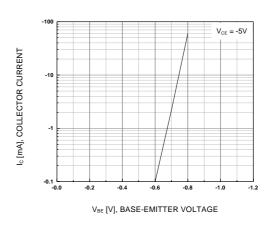


Figure 4. Base-Emitter On Voltage

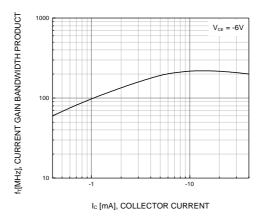


Figure 6. Current Gian Bandwidth Product

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